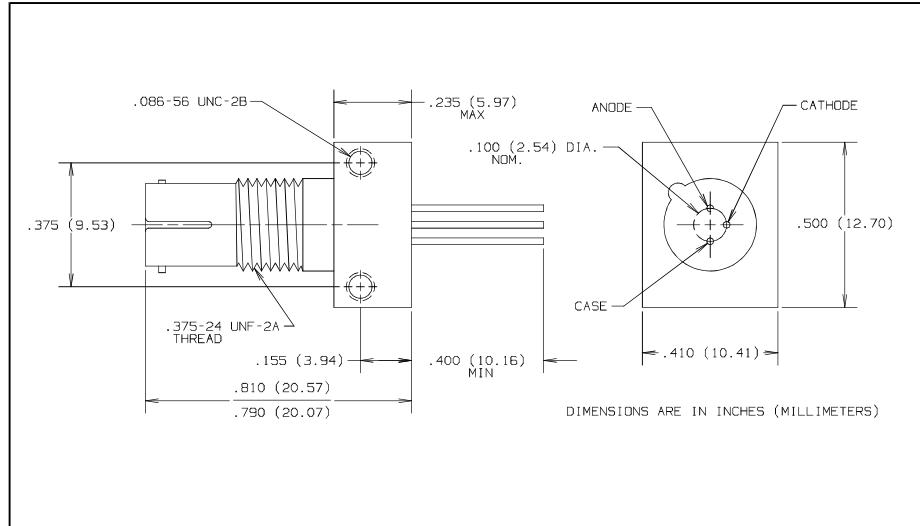
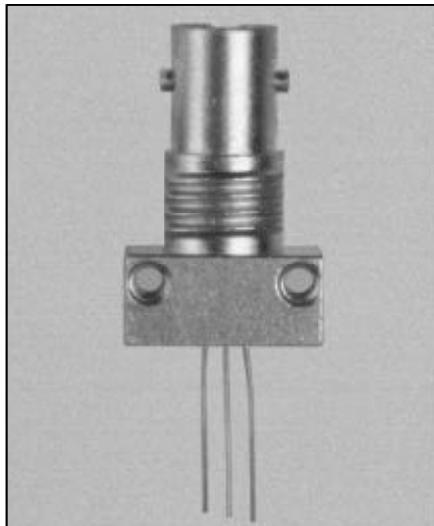


Fiber Optic GaAlAs High Speed LED in ST* Receptacle Types OPF342A, OPF342B, OPF342C, OPF342D



Features

- Component pre-mounted and ready to use
- Pre-tested with fiber to assure performance
- Popular ST* style receptacle
- High Speed
- Electrically isolated from case

Description

The OPF342 series LED consists of a hermetic LED, pre-mounted and aligned in an ST* receptacle. This configuration is designed for PC board or panel mounting. Includes lock washer and jam nut, two 2-56 screws, and a dust cap.

The LED's are designed to interface with multimode optical fibers from 50/125 to 200/300 microns.

*ST is a registered trademark of AT&T.

Absolute Maximum Ratings ($T_A = 25^\circ C$ unless otherwise noted)

Reverse Voltage	1.0 V
Continuous Forward Current	100 mA ⁽⁴⁾
Storage Temperature Range	-55° C to +150° C
Operating Temperature Range	-40° C to +125° C
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 sec. with soldering iron]	240° C ⁽¹⁾

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 sec. max when flow soldering.
- (2) Graded index fiber, 50 μm core, N.A. = 0.20.
- (3) To convert radiant power output to dBm, use the following expression $\text{dBm} = 10 \log (\mu\text{W}/1000)$.
- (4) Derate linearly @ 1.0 mA/° C above 25° C.
- (5) Prebias @ 5 mA current.

LED Burn-in

All LED's are subject to 100% burn-in testing. Test conditions are 96 hours at 100 mA continuous current in 25° C ambient.

TYPICAL COUPLED POWER into OPTICAL FIBER

Typical Coupled Power $I_F = 100 \text{ mA} @ 25^\circ \text{ C}$						
Fiber	Refractive Index	N.A.	OPF342D	OPF342C	OPF342B	OPF342A
50/125 μm	Graded	0.20	7.5 μW	12.5 μW	18 μW	25 μW
62.5/125 μm	Graded	0.28	14 μW	22 μW	34 μW	45 μW
100/140 μm	Graded	0.29	38 μW	62 μW	95 μW	125 μW
200/300 μm*	Step	0.41	140 μW	235 μW	340 μW	475 μW

*PCS - Plastic Clad Silica

Types OPF342A, OPF342B, OPF342C, OPF342D

Electrical Characteristics ($T_A = 25^\circ C$ unless otherwise noted)

SYMBOL	PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITIONS
P _O	Radiant Power Output	OPF342D	5.0	7.5			
		OPF342C	10.0	12.5		μW	I _F = 100 mA ⁽²⁾
		OPF342B	15.0	18.0			
		OPF342A	20.0	25.0			
V _F	Forward Voltage			1.8	2.0	V	I _F = 100 mA
λ _P	Peak Output Wavelength	830	850	870		nm	I _F = 50 mA
B	Spectral Bandwidth Between Half Power Points			35		nm	I _F = 50 mA
t _r	Output Rise Time			4.5	6.0	ns	I _F = 100 mA, 10%-90% ⁽⁵⁾
t _f	Output Fall Time			4.5	6.0	ns	I _F = 100 mA, 90%-10% ⁽⁵⁾

Typical Performance Curves

